## NSN 5961-01-549-2989

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-549-2989 **Inclosure Material:** Metal **Overall Length:** 7.3 millimeters **Overall Height:** 2.3 millimeters **Overall Width:** 6.5 millimeters **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 forward gate to source voltage **Current Rating Per Characteristic:** -10.00 amperes repetitive peak forward current peak **Power Rating Per Characteristic:** 37.0 watts small-signal input power, common-emitter peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**